

INCHANGE SEMICONDUCTOR

isc Silicon PNP Power Transistor

2SA1744

DESCRIPTION

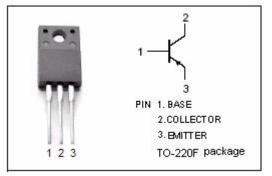
- Collector-Emitter Sustaining Voltage-
 - : V_{CEO(SUS)}= -60V(Min)
- High DC Current Gain-
- : h_{FE}= 100(Min)@ (V_{CE}= -2V , I_C= -3A)
- · Low Saturation Voltage-
 - : $V_{CE(sat)}$ = -0.3V(Max)@ (I_C= -8A, I_B= -0.4A)
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

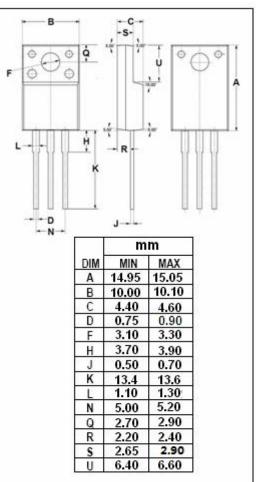
APPLICATIONS

 This type of power transistor is developed for high-speed switching and features a high h_{FE} at low V_{CE(sat)}, which is ideal for use as a driver in DC/DC converters and actuators.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	-100	V	
V _{CEO}	Collector-Emitter Voltage	-60	V	
V _{EBO}	Emitter-Base Voltage	-7.0	V	
lc	Collector Current-Continuous	-15	А	
I _{CM}	Collector Current-Pulse	-30	А	
I _B	Base Current-Continuous	-7.5	А	
PT	Total Power Dissipation @T _c =25℃	30	W	
	Total Power Dissipation @T _a =25°C	2.0		
TJ	Junction Temperature	150	°C	
T _{stg}	Storage Temperature	-55~150	°C	





isc website: www.iscsemi.com



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ELECTRICAL CHARACTERISTICS

Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = -8.0A ; I _B = -0.8A, L= 1mH	-60			V
V _{CE} (sat)-1	Collector-Emitter Saturation Voltage	I _C = -8A; I _B = -0.4A			-0.3	V
V _{CE(sat)-2}	Collector-Emitter Saturation Voltage	I _C = -12A; I _B = -0.6A			-0.5	V
V _{BE(sat)-1}	Base-Emitter Saturation Voltage	I _C = -8A; I _B = -0.4A			-1.2	V
V _{BE(sat)-2}	Base-Emitter Saturation Voltage	I _C = -12A; I _B = -0.6A			-1.5	V
I _{СВО}	Collector Cutoff Current	V _{CB} = -60V ; I _E =0			-10	μA
I _{EBO}	Emitter Cutoff Current	V _{EB} = -5V; I _C =0			-10	μA
h _{FE-1}	DC Current Gain	I _C = -1.5A; V _{CE} = -2V	100			
h _{FE-2}	DC Current Gain	I _C = -3.0A; V _{CE} = -2V	100		400	
h _{FE-3}	DC Current Gain	Ic= -8.0A; V _{CE} = -2V	60			

h_{FE-2} Classifications

М	L	к
100-200	150-300	200-400

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